Vishay Semiconductors

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Hyperfast Rectifier, 30 A FRED Pt®



2L TO-220 FullPAK

PRIMARY CHARACTERISTICS						
I _{F(AV)} 30 A						
V _R	600 V					
V _F at I _F	1.4 V					
t _{rr} (typ.)	27 ns					
T _J max.	175 °C					
Package	2L TO-220 FullPAK					
Circuit configuration	Single					

FEATURES

- Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package ($V_{INS} = 2500 V_{RMS}$)
- True 2 pin package
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Peak repetitive reverse voltage	V _{RRM}		600	V					
Average rectified forward current in DC	I _{F(AV)}	T _C = 51 °C	30	^					
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	180	A					
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-			
Forward voltage	V _F	I _F = 30 A	-	2.0	2.65	V		
		I _F = 30 A, T _J = 150 °C	-	1.4	1.8			
Powerse lookage ourrept		$V_{\rm R} = V_{\rm R}$ rated	-	0.02	30	μA		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	50	300	μΑ		
Junction capacitance	CT	V _R = 600 V	-	20	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH		

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1



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A, } dI_F/dt =$	= 50 A/µs, V _R = 30 V	-	26	35			
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 30 A, dI _F /dt = 200 A/μs, V _R = 200 V	-	26	-	A nC		
		T _J = 125 °C		-	70	-			
Dook rooovony ourront	I _{RRM}	T _J = 25 °C		-	3.5	-			
Peak recovery current		T _J = 125 °C		-	7.6	-			
Reverse recovery charge	0	T _J = 25 °C		-	50	-			
	Q _{rr}	T _J = 125 °C		-	280	-	nc		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction-to-case	R _{thJC}		-	3.2	3.8			
Thermal resistance, junction-to-ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W		
Typical thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-			
Weight			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style 2L TO-220 FullPAK	ETH3006FP					



VS-ETH3006FP-M3

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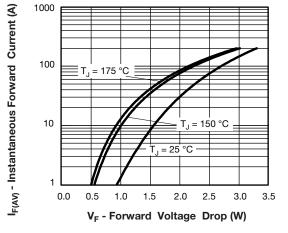


Fig. 1 - Typical Forward Voltage Drop Characteristics

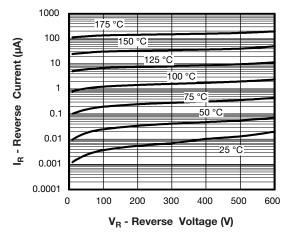


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

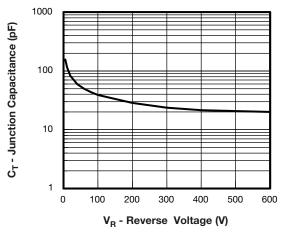


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

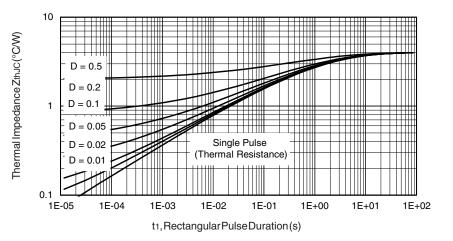


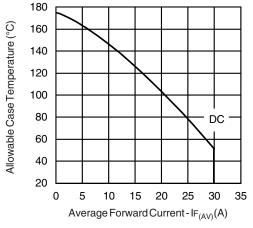
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

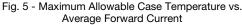
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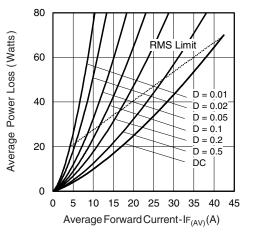


Fig. 6 - Forward Power Loss Characteristics

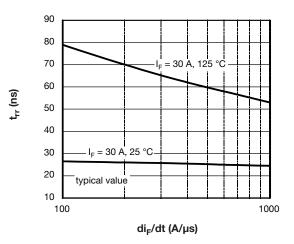
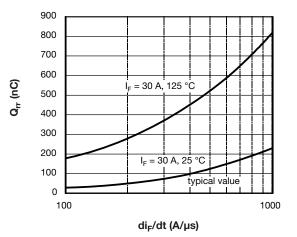


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt





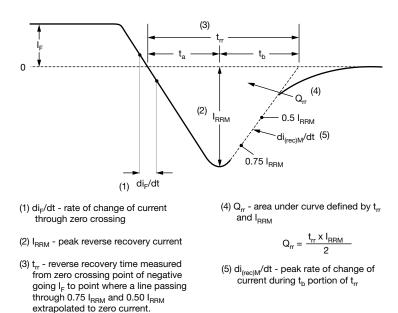


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

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Device code	VS-	Е	т	н	30	06	FP	-M3
			•				••	
		2	3	4	5	6	7	8
	1 -	· Visł	nay Sem	nicondu	ctors pr	oduct		
	2 -	Circ	cuit cont	figuratio	n:			
		E =	single					
	3 -	- T =	TO-220)				
	4 -	H =	hyperfa	ast recov	very tim	е		
	5 -	Cur	rent coo	de: 30 =	30 A			
	6 -	Volt	tage coo	de: 06 =	600 V			
	7 -	FP :	= 2L TO	-220 Fu	IIPAK			
	8 -	Env	ironmer	ntal digit	:			
		-M3	3 = halog	gen-free	e, RoHS	-compli	ant, and	d termir

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-ETH3006FP-M3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96157				
Part marking information	www.vishay.com/doc?95392				
SPICE model	www.vishay.com/doc?96817				

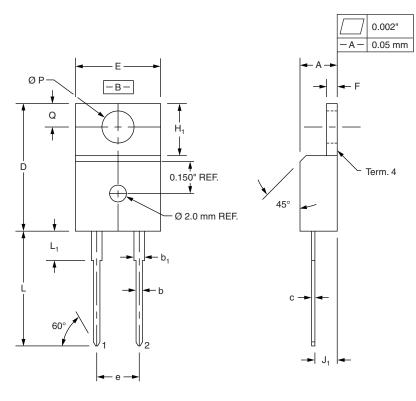




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True 2 Pin TO-220

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCH	IES	
STMBOL	MIN.	MAX.	MIN.	MAX.	
А	4.32	4.57	0.170	0.180	
b	0.71	0.91	0.028	0.036	
b ₁	1.15	1.39	0.045	0.055	
с	0.36	0.53	0.014	0.021	
D	14.99	15.49	0.590	0.610	
E	10.04	10.41	0.395	0.410	
e	5.08	BSC	0.200 BSC		
F	1.22	1.37	0.048	0.054	
H ₁	5.97	6.47	0.235	0.255	
J ₁	2.54	2.79	0.100	0.110	
L	13.47	13.97	0.530	0.550	
L ₁ ⁽¹⁾	3.31	3.81	0.130	0.150	
ØP	3.79	3.88	0.149	0.153	
Q	2.60	2.84	0.102	0.112	

Notes

 $^{\left(1\right)}$ Lead dimension and finish uncontrolled in L_{1}

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

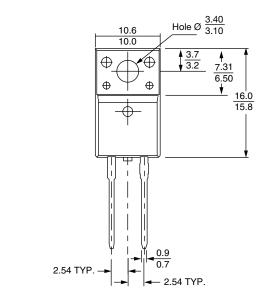
Controling dimension: Inch

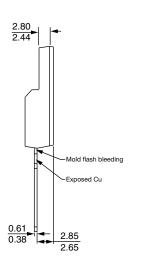


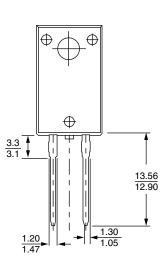
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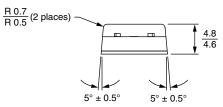
DIMENSIONS in millimeters







Bottom view





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